



SANYO SEMICONDUCTOR

NPN	PNP
TIP140	TIP145
TIP141	TIP146
TIP142	TIP147

DARLINGTON COMPLEMENTARY SILICON POWER TRANSISTORS

60-80-100 VOLTS, 10 AMPERE

HIGH CURRENT GAIN $h_{FE} = 4000$ typ. @ 3V, 5A
 LOW SATURATION VOLTAGE $V_{CE(SAT)} = 1.0V$ typ. @ 5A
 MONOLITHIC CONSTRUCTION WITH BUILT-IN
 (1) BASE-EMITTER RESISTORS AND
 (2) COLLECTOR-EMITTER DIODE

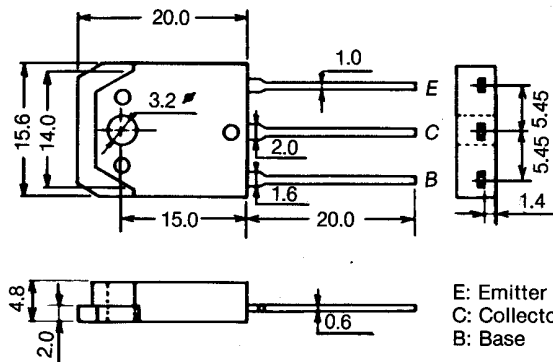
ABSOLUTE MAXIMUM RATINGS @ $T_a = 25^\circ C$

RATING	SYMBOL	TIP140, TIP145	TIP141, TIP146	TIP142, TIP147	UNIT
COLLECTOR-EMITTER VOLTAGE	V_{CEO}	60	80	100	Vdc
COLLECTOR-BASE VOLTAGE	V_{CB}	60	80	100	Vdc
EMITTER-BASE VOLTAGE	V_{EB}	← 5.0 →			Vdc
COLLECTOR CURRENT- CONTINUOUS PEAK	I_C	← 10 → ← 15 →			A _{dc}
TOTAL POWER DISSIPATION @ $T_C = 25^\circ C$	P_D	← 125 →			W
TOTAL POWER DISSIPATION @ $T_A = 25^\circ C$	P_D	← 3.5 →			W
OPERATING AND STORAGE JUNCTION TEMPERATURE RANGE	T_J, T_{stg}	← - 55 to + 150 →			$^\circ C$

OUTLINE DIMENSION

JEDEC: TO-3P

UNIT: MM

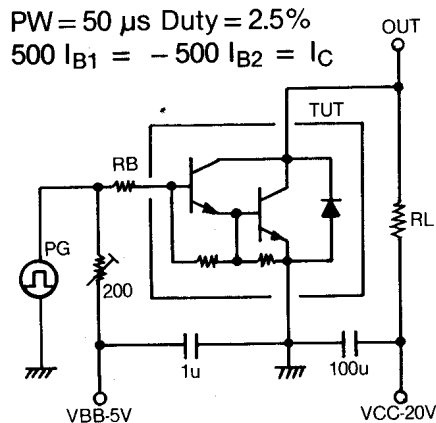


E: Emitter
 C: Collector
 B: Base

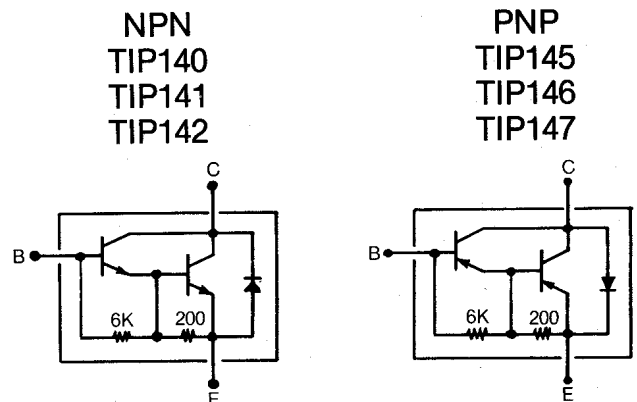
ELECTRICAL CHARACTERISTICS @ Ta = 25°C

CHARACTERISTIC	SYMBOL	MIN	MAX	UNIT
COLLECTOR-EMITTER SUSTAINING VOLTAGE (I _C = 30 mA _{dc} , I _B = 0)	V _{CE(SUS)}	60	—	V _{dc}
TIP140, TIP145		80	—	
TIP141, TIP146		100	—	
TIP142, TIP147				
COLLECTOR CUTOFF CURRENT (V _{CE} = 30 V _{dc} , I _B = 0)	I _{CEO}	—	2.0	mA _{dc}
(V _{CE} = 40 V _{dc} , I _B = 0)		—	2.0	
(V _{CE} = 50 V _{dc} , I _B = 0)		—	2.0	
COLLECTOR CUTOFF CURRENT (V _{CB} = 60 V _{dc} , I _E = 0)	I _{CBO}	—	1.0	mA _{dc}
(V _{CB} = 80 V _{dc} , I _E = 0)		—	1.0	
(V _{CB} = 100 V _{dc} , I _E = 0)		—	1.0	
EMITTER CUTOFF CURRENT (V _{BE} = 5.0 V _{dc} , I _C = 0)	I _{EBO}	—	2.0	mA _{dc}
DC CURRENT GAIN (I _C = 5.0 A _{dc} , V _{CE} = 4.0 V _{dc})	h _{FE}	1000	—	—
(I _C = 10.0 A _{dc} , V _{CE} = 4.0 V _{dc})		500	—	
COLLECTOR-EMITTER SATURATION VOLTAGE (I _C = 5.0 A _{dc} , I _B = 10 mA _{dc})	V _{CE(SAT)}	—	2.0	V _{dc}
(I _C = 10.0 A _{dc} , I _B = 40 mA _{dc})		—	3.0	
BASE-EMITTER ON VOLTAGE (I _C = 10.0 A _{dc} , V _{CE} = 4.0 V _{dc})	V _{BE(ON)}	—	3.0	V _{dc}
GAIN BANDWIDTH PRODUCT (I _C = 5.0 A, V _{CE} = 5.0V)	f _T	20 typ.		mHz

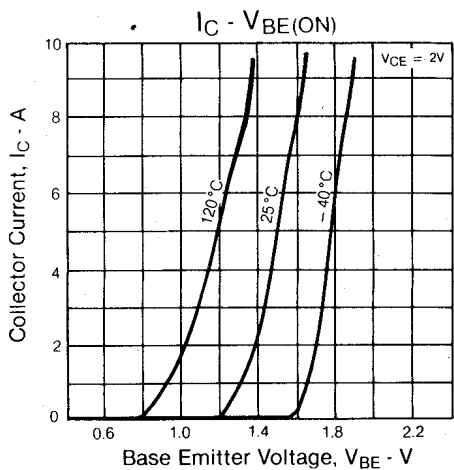
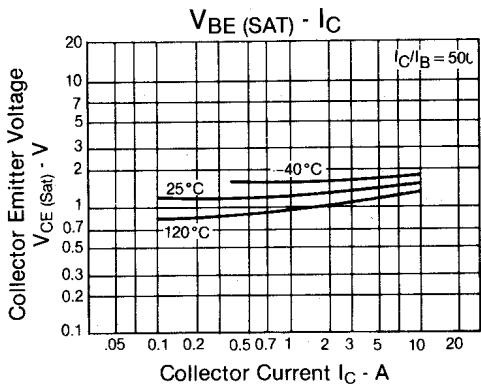
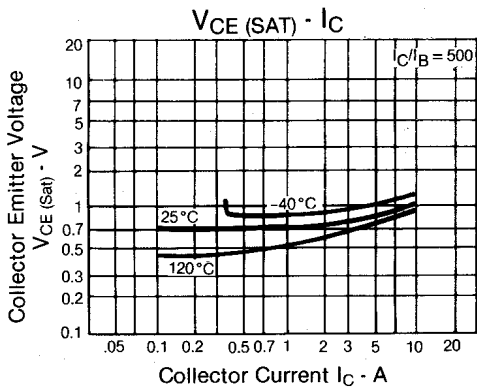
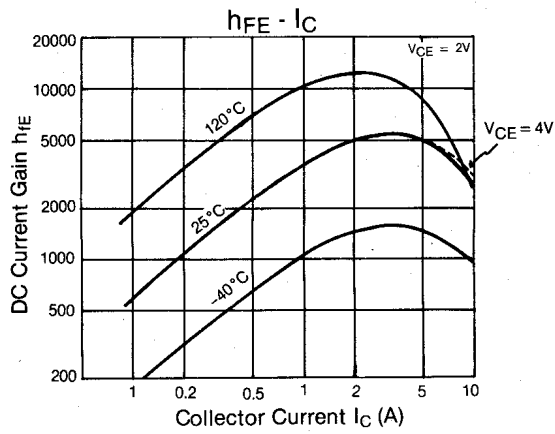
SWITCHING TIME TEST CIRCUIT



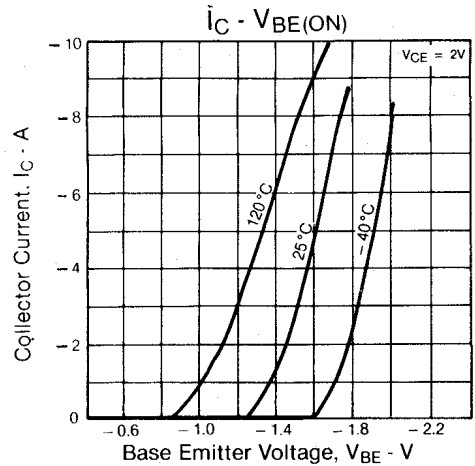
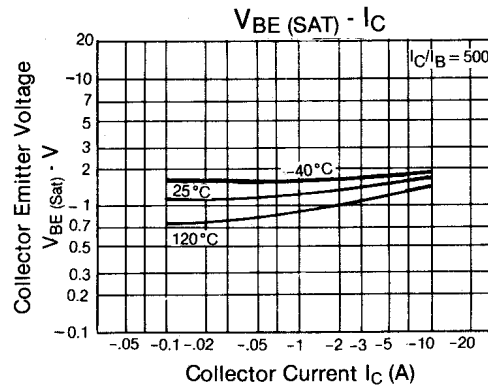
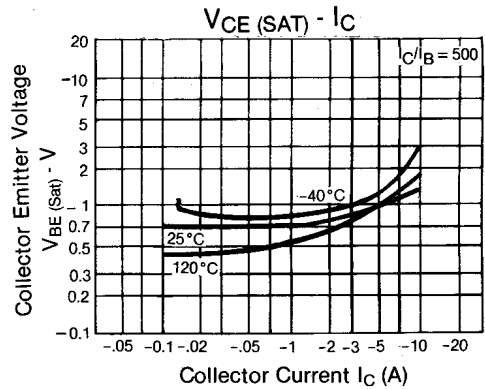
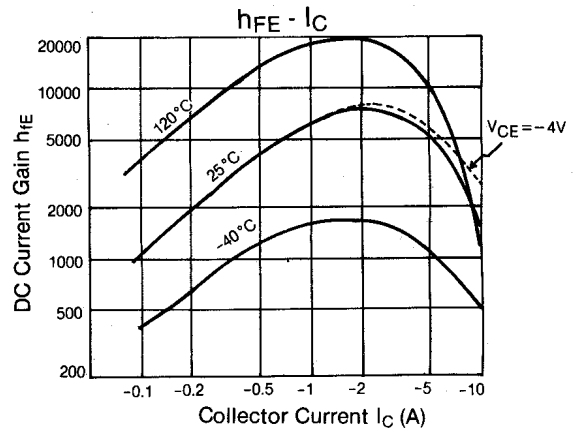
DARLINGTON SCHEMATIC



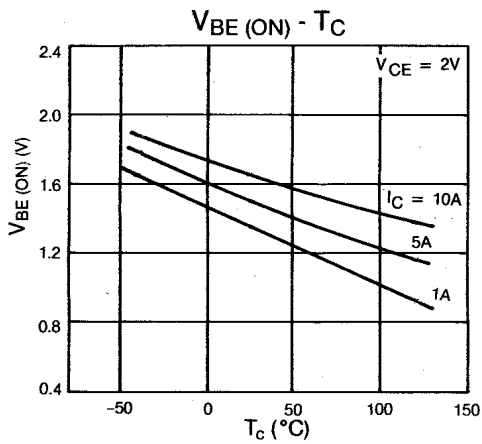
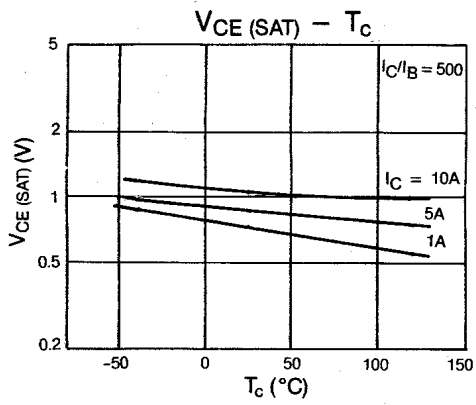
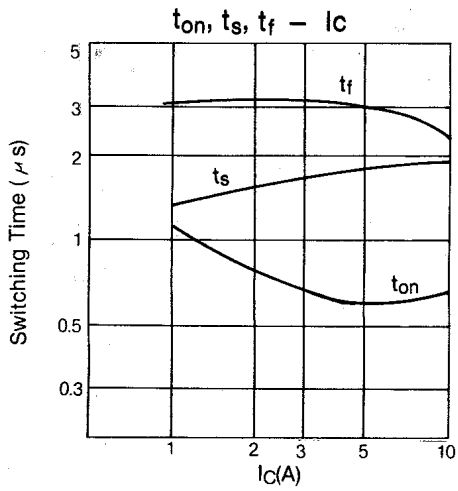
NPN
TIP 140, TIP 141, TIP 142



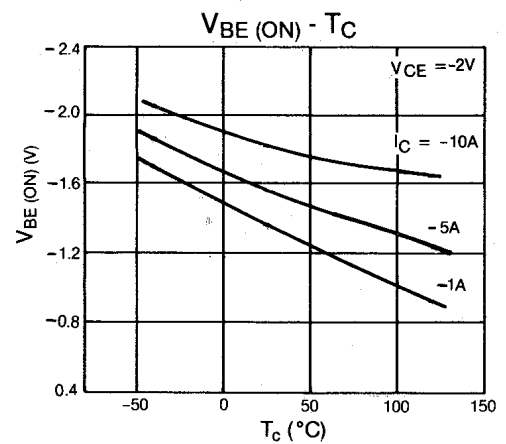
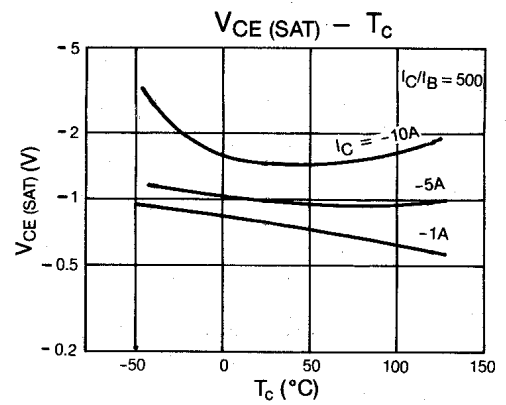
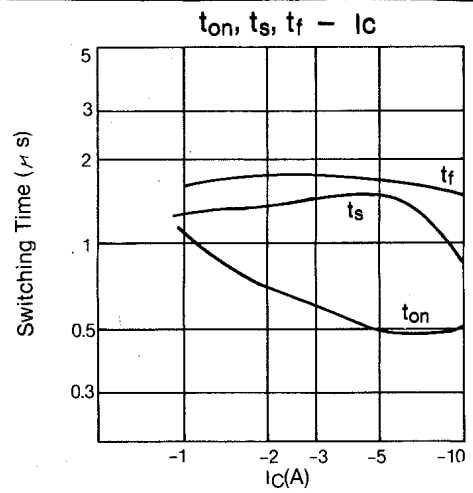
PNP
TIP 145, TIP 146, TIP 147



NPN
TIP 140, TIP 141, TIP 142



PNP
TIP 145, TIP 146, TIP 147



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